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High Field Magnetotransport and Specific Heat in YbAgCu₄

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Abstract

The electrical resistivity (ρ) and magnetoresistance of polycrystalline YbAgCu₄ have been measured at temperatures between 25 mK and 300 K, and at magnetic fields (B) to 18 T. The magnetoresistance $(\rho(B) - \rho(0))/\rho(0)$ is positive at all temperatures below 200 K and reaches its maximum of 60% at 18 T and 25 mK. The field- and temperature-dependent resistivity does not scale in a simple way. The opposite magnetoresistance behaviors at ambient and high pressure can be explained qualitatively by crystal-field effects lifting the degeneracy of the $J=7/2$ groundstate. The linear coefficient of specific heat (γ) measured at fields to 10 T shows a quadratic field dependence. We do not find a linear relation between γ^2 and A , the T^2 -coefficient of the temperature-dependent resistivity, with field as the implicit parameter.

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YbAgCu₄ is one of the few Yb-based intermetallic compounds with a large linear coefficient of specific heat $\gamma = 245 \text{ mJ/mole K}^2$ [1]. Its temperature-dependent magnetic susceptibility and specific heat are described well by the Coqblin-Schrieffer model with $J=7/2$ and a characteristic energy scale $T_0 \approx 160 \text{ K}$ [1, 2]. Inelastic neutron scattering [3] finds no evidence for well-defined crystal-field excitations, consistent with the susceptibility results. Application of pressure causes a rapid decrease in T_{max} , the temperature at which the resistivity is a maximum, and an increase of the T^2 -coefficient of resistivity (A) [4, 5], suggesting that $\partial T_0/\partial P < 0$. At sufficiently high pressures, it is distinctly possible that T_0 becomes much less than crystal-field splitting of the J-multiplet, the ground state degeneracy is at least partially lifted and spin fluctuations increasingly dominate electrical transport at low temperatures. This possibility could provide a partial explanation for the significantly different magnetoresistive behavior of YbAgCu₄ at low and high pressures: at ambient pressure the magnetoresistance is positive for $T < 20 \text{ K}$ and fields less than 10 T [4] but for pressures greater than 70 kbar, the magnetoresistance is strongly negative [5]. To explore in more detail the origin of these opposite behaviors at low and high pressure (at large and small T_0 , respectively) we have measured the specific heat (C), of YbAgCu₄ in fields to 10 T for temperatures $4 \leq T \leq 10 \text{ K}$ and the electrical resistivity at fields to 18 T and temperatures between 25 mK and 300 K.

The preparation of polycrystalline samples has been described previously [5]. Electrical resistivity was measured using a four lead ac resistance bridge (LR-400) operating at 17 Hz. The magnetic field was applied perpendicular to the current (transverse geometry) and was generated by a 20 T superconducting magnet at the National High Magnetic Field Laboratory, Los Alamos Facility. The specific heat was measured in a small mass calorimeter utilizing a relaxation method.

Figure 1(a) shows the temperature-dependent resistivity ρ of YbAgCu₄ in magnetic fields from 0 to 18 T. For $T < 15 \text{ K}$, the curves can be fit to $\rho(T, B) = \rho_0(B) + A(B) T^2$, which is shown explicitly in the inset of Fig. 1(a). The magnetoresistance $(\rho(B) - \rho(0))/\rho(0)$ is positive for all temperatures less than 200 K and reaches its maximum of 60 % at 18 T and 25 mK. The monotonic evolution of the magnetoresistance with increasing temperature is shown in Fig. 1(b). At each temperature $\Delta\rho/\rho(0) \propto B^\alpha$, with $\alpha \approx 1.5$. The

data shown in Fig. 1(a) do not scale in any simple way, contrary to what has been found for pressure-induced changes in the resistivity [6]. For example, plots of ρ/ρ_i vs. T/T_i , where ρ_i and T_i are the resistivity and temperature where $\partial\rho/\partial T$ is a maximum, do not scale the curves, nor does plotting the data in a Kohler-form $\Delta\rho/\rho(0) = f(B/\rho(0))$, or as ρ vs. $T\sqrt{A}$.

The specific heat divided by temperature is plotted in Fig. 2 as a function of T^2 for various applied fields. Solid lines are least squares fits to the data and yield the linear coefficients γ , which are shown in Fig. 3 to increase linearly with B^2 . With the usual assumption that $\gamma \propto 1/T_0$, this implies that T_0 is inversely proportional to B^2 . From the linear relation $\gamma \propto \sqrt{A}$ found [7] for several heavy fermion compounds at zero field, we would expect A to increase as B^4 . Figure 3 shows the measured change in A as a function of B^2 . Though $A(B)$ increases superlinearly in B^2 for $B \leq 12$ T, at higher fields A varies approximately as B^2 . The inset of Fig. 3 clearly demonstrates the absence of a linear correlation between γ and \sqrt{A} for $B \leq 10$ T. This is contrary to what is found [8] when pressure is the implicit variable.

Qualitatively we can understand the different field responses of YbAgCu_4 at zero and high pressures as follows. Okiji and Kawakami [9] have shown for the $J=5/2$ Coqblin-Schrieffer model that γ increases approximately quadratically with field for $B < 0.4 T_0$ ($B < 95$ T for $T_0 = 160$ K). We expect a similar situation to hold for $J=7/2$, i.e. YbAgCu_4 at ambient pressure. From the usually assumed relationship between γ and A , we, therefore, would expect A to increase with B , as found at ambient pressure. On the other hand, for $J=1/2$, γ decreases strongly with field [9, 10] and we should find A decreasing with field as well, as observed at high pressures [5]. Although, a change in groundstate degeneracy appears to account qualitatively for observations at ambient and high pressure, there remain quantitative questions to be addressed. The 10 % increase in γ at 10 T is larger than predicted, at least for $J=5/2$. The large change in ρ_0 in applied field, for either ambient or high pressures, lacks a simple explanation, as does the field dependence of A and, more generally, of $\rho(T)$. Additional high field measurements on heavy fermion systems would be helpful to identify to what extent these features are general.

Acknowledgments

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Figure Captions:

Fig. 1(a). Resistivity ρ as a function of temperature T at magnetic fields of 0 (bottom curve), 6, 10, 14 and 18 T (top curve). Inset: Resistivity vs. temperature squared at the same fields. The lines are linear fits to the data. (b). Magnetoresistance $(\rho(B)-\rho(0))/\rho(0)$ as a function of magnetic field B at different temperatures.

Fig. 2. Specific heat C divided by temperature T as a function of T^2 at different magnetic fields (0, 2, 4, 6, 8, 10 T, from bottom to top). The lines are linear least squares fits.

Fig. 3. Linear coefficient of specific heat γ (left axis) and T^2 -coefficient of resistivity A (right axis) as a function of magnetic field squared. Inset: γ vs. $A^{1/2}$ with field as the implicit variable.

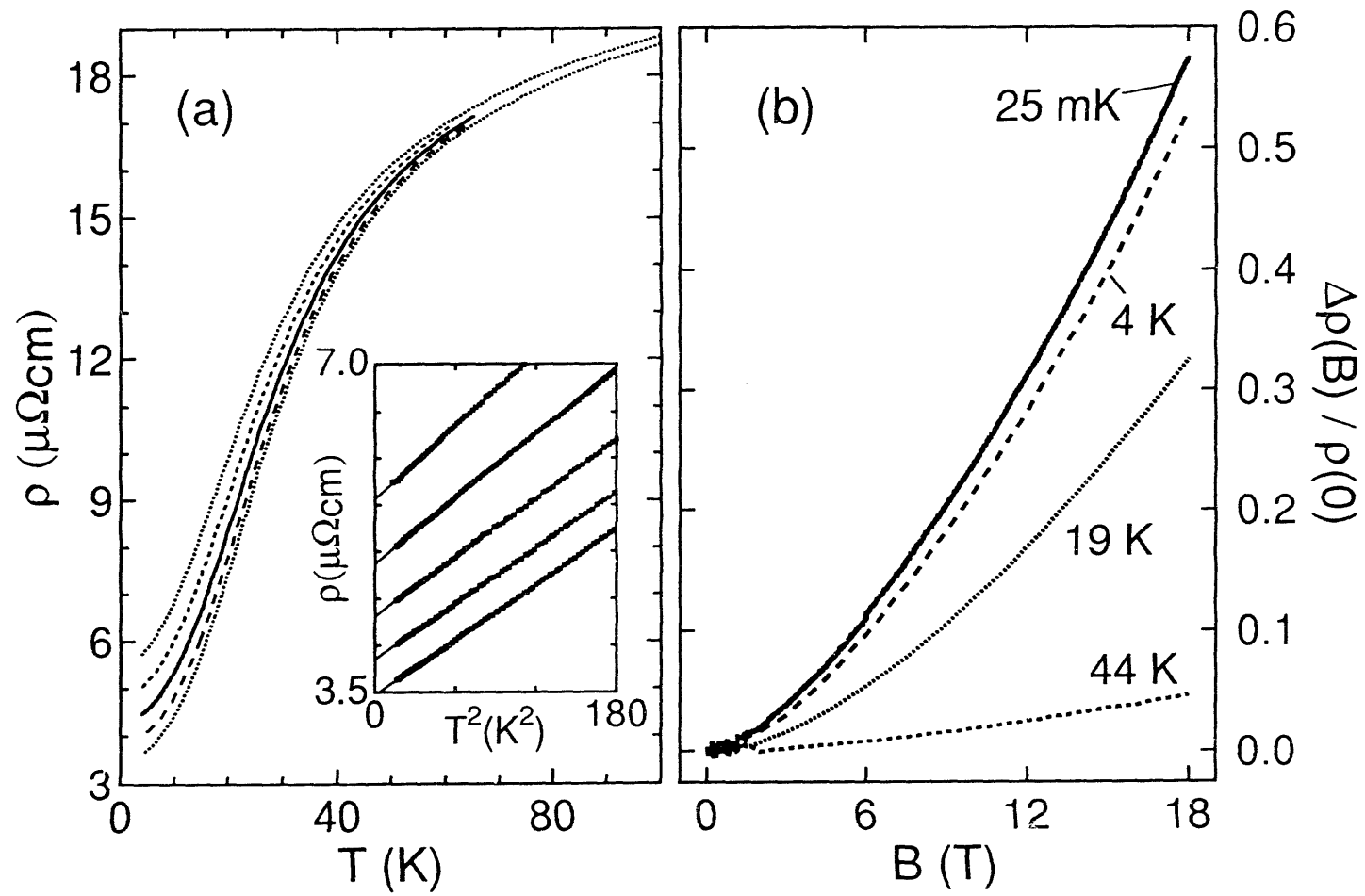


Fig. 1
Lacerda et al.

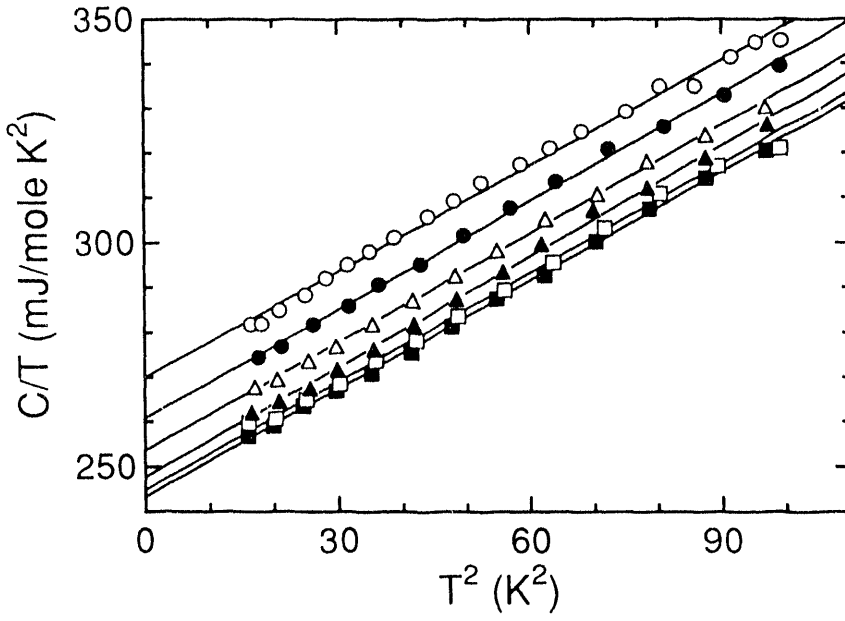


Fig. 2

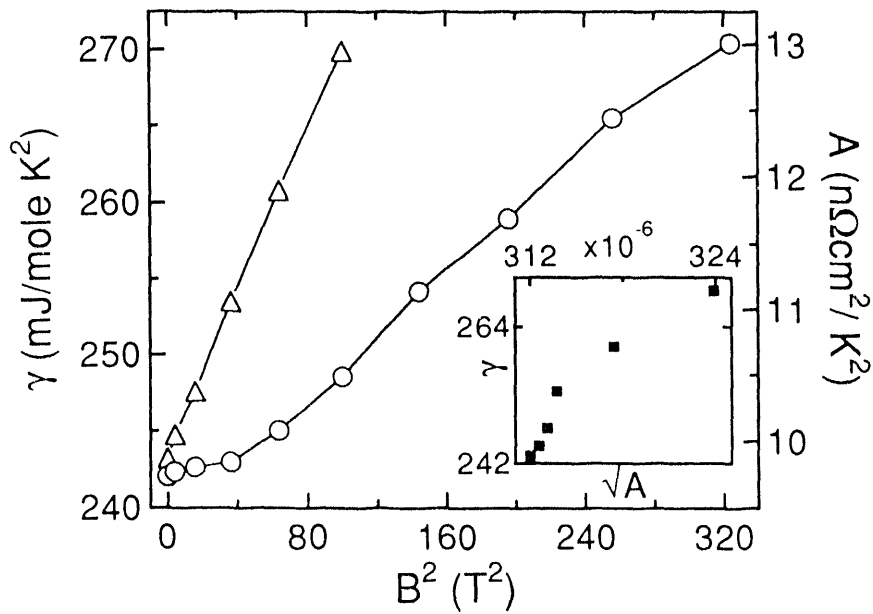


Fig. 3